

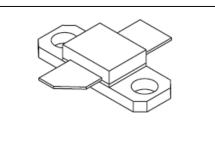
The RF Line NPN Silicon Power Transistor 6.0W, 1.6GHz, 28V

M/A-COM Products Released - Rev. 07.07

Designed for 28 V microwave large–signal, common base, Class C, CW amplifier applications in the range 1600-1640~MHz.

- Specified 28 V, 1.6 GHz Class C characteristics
 Output power = 6 W
 Minimum gain = 7.4 dB, @ 6 W
 Minimum efficiency = 40% @ 6 W
- Characterized with series equivalent large—signal parameters from 1500 MHz to 1700 MHz
- Silicon nitride passivated
- Gold metalized, emitter ballasted for long life and resistance to metal migration

Product Image



CASE 395C-01, STYLE 2

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Collector–Emitter Voltage	V _{CES}	60	Vdc
Emitter–Base Voltage	V _{EBO}	4.0	Vdc
Collector-Current	Ic	1.0	Adc
Total Device Dissipation @ T _C = 25°C Derate above 25°C	P _D	26 0.15	Watts W/°C
Storage Temperature Range	T _{stg}	-65 to +150	°C

THERMAL CHARACTERISTICS

Therm	al Resistance — Junction to Case (1) (2)	R _{eJC}	6.8	°C/W	

⁽¹⁾ Thermal measurement performed using CW RF operating condition.

⁽²⁾ Thermal resistance is determined under specified RF operating conditions by infrared measurement techniques.

[•] Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300

Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298
 Visit www.macomtech.com for additional data sheets and product information.



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ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS	•	•	•		•
Collector–Emitter Breakdown Voltage (I _C = 40 mAdc, V _{BE} = 0)	V _{(BR)CES}	55	_	_	Vdc
Collector–Base Breakdown Voltage (I _C = 40 mAdc, I _E = 0)	V _(BR) CBO	55	_	_	Vdc
Emitter–Base Breakdown Voltage (I _E = 2.5 mAdc, I _C = 0)	V _{(BR)EBO}	4.0	_	_	Vdc
Collector Cutoff Current (VCE = 28 Vdc, V _{BE} = 0)	I _{CES}	_	_	2.5	mAdc
ON CHARACTERISTICS	•		•		
DC Current Gain (I _{CE} = 0.2 Adc, V _{CE} = 5.0 Vdc)	h _{FE}	20	_	80	_
DYNAMIC CHARACTERISTICS					•
Output Capacitance (V _{CB} = 28 Vdc, f = 1.0 MHz)	C _{ob}	11	_	_	pf
FUNCTIONAL TESTS		•	•	•	
Common–Base Amplifier Power Gain (V _{CC} = 28 Vdc, P _{out} = 6 Watts, f = 1600/1640 MHz)	G _{pe}	7.4	_	_	dB
Collector Efficiency (V _{CC} = 28 Vdc, P _{out} = 6 Watts, f = 1600/1640 MHz)	η	40	45	_	%
Return Loss (V _{CC} = 28 Vdc, P _{out} = 6 Watts, f = 1600/1640 MHz)	I _{RL}	_	8.0	_	dB
Output Mismatch Stress (V _{CC} = 28 Vdc, P _{out} = 6 Watts, f = 1600 MHz, Load VSWR = 3:1 all phase angles at frequency of test)	Ψ	No Degradation in Output Power			

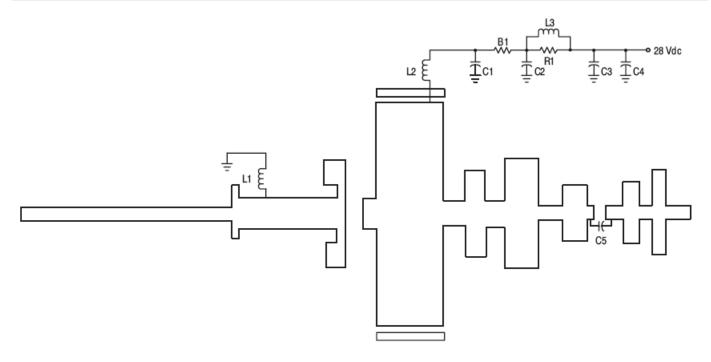
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Board Material – Teflon® Glass Laminate Dielectric Thickness – 0.30″, ϵ_{r} = 2.55″, 2.0 oz. Copper

B1Fair Rite Bead on #24 WireC4 $47 \mu F$, 50 V, Electrolytic CapC1, C5100 pF, B Case, ATC Chip CapL1, L23 Turns, #18, 0.133" ID, 0.15" LongC2 $0.1 \mu F$, Dipped Mica CapL39 Turns, #24 EnamelC3 $0.1 \mu F$, Chip CapR182 Ω , 1.0 W, Carbon Resistor

Figure 1. MRF16006 Test Fixture Schematic

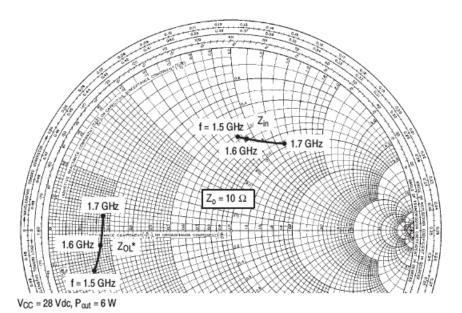
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Z_{OL}* = Conjugate of the optimum load impedance into which the device output operates at a given output power, voltage and frequency.

Figure 2. Series Equivalent Input/Output Impedance



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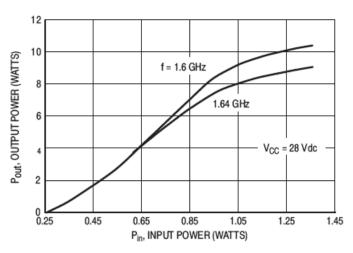


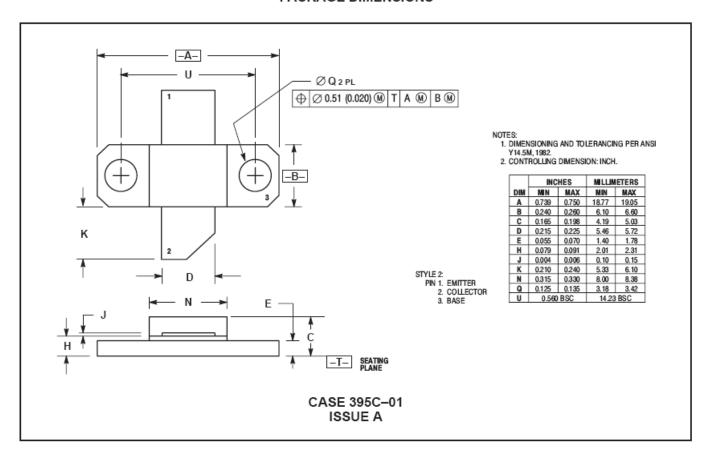
Figure 3. Output Power versus Input Power



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PACKAGE DIMENSIONS



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